



**THE DATASHEET OF
SIP32462DB-T2-GE1**



50 mΩ, Slew Rate Controlled Load Switch in WCSP

DESCRIPTION

The SiP32460, SiP32461, and SiP32462 are slew rate controlled integrated high side load switches that operate over the input voltage range from 1.2 V to 5.5 V.

This series of design features slew rate control, reverse blocking when switch is off, output discharge, and control logic pulldown. The devices are logic high enabled.

The SiP32460, SiP32461, and SiP32462 are available in compact wafer level WCSP package, WCSP4 0.76 mm x 0.76 mm with 0.4 mm pitch.

FEATURES

- Low input voltage, 1.2 V to 5.5 V
- Low R_{on} , 54 mΩ/typ. at 3 V
- Slew rate control
- Compatible with 1.2 V to 3.3 V logic
- 7.5 μs turn-on time at 5 V (SiP32462)
- Reverse current blocking when switch is off
- Integrated output discharge switch (SiP32461)
- Integrated pulldown resistor at “EN”
- For enable “low” see SiP32467 and SiP32468
- 4-bump WCSP package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



APPLICATIONS

- Smart phones
- GPS and portable media players
- Tablet computers
- Medical and healthcare equipment
- Industrial and instrumentation
- Game consoles

TYPICAL APPLICATION CIRCUIT

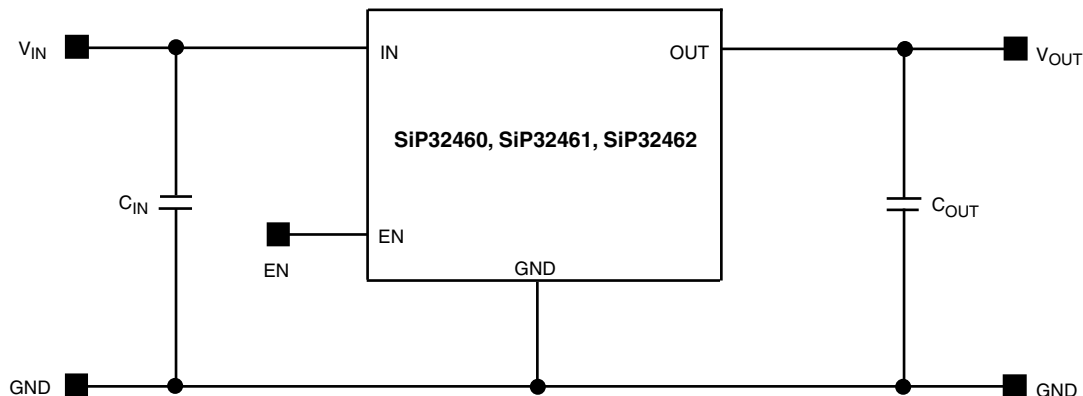


Fig. 1 - Typical Application Circuit

ORDERING INFORMATION						
PART NUMBER	PACKAGE	t_{on} (μs)	$R_{DISCHARGE}$	MARK CODE	TEMPERATURE RANGE	
SiP32460DB-T2-GE1	WCSP4 (2x2), 0.4 mm pitch	300	No	AF	-40 °C to +85 °C	
SiP32461DB-T2-GE1	WCSP4 (2x2), 0.4 mm pitch	300	Yes	AG	-40 °C to +85 °C	
SiP32462DB-T2-GE1	WCSP4 (2x2), 0.4 mm pitch	7.5	No	AH	-40 °C to +85 °C	



ABSOLUTE MAXIMUM RATINGS			
PARAMETER	CONDITIONS	LIMIT	UNIT
Supply input voltage V_{IN}	Reference to GND	-0.3 to 6.5	V
Output voltage V_{OUT}	Reference to GND	-0.3 to 6.5	
Output voltage V_{OUT}	Pulse at 1 ms reference to GND ^a	-1.6	
Enable input voltage EN	Reference to GND	-0.3 to 6.5	
Maximum continuous switch current		1.2	A
Maximum pulse switch current	Pulse at 1 ms, 10 % duty cycle	2	
ESD rating (HBM)		4000	V
Thermal resistance		205	°C/W
Maximum power dissipation	$T_A = 25\text{ °C}$	300	mW
Temperature			
Operating temperature		-40 to +85	°C
Operating junction temperature		125	
Storage temperature		-65 to +150	

Note

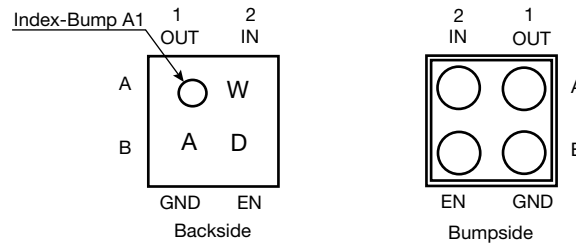
a. Negative current injection up to 300 mA

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE				
ELECTRICAL PARAMETER	MINIMUM	TYPICAL	MAXIMUM	UNIT
Input voltage (V_{IN})	1.2	-	5.5	V
Output voltage (V_{OUT})	1.2	-	5.5	

SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED $V_{IN} = 1.2\text{ V to }5.5\text{ V}$, $T_A = -40\text{ °C to }+85\text{ °C}$ (typical values are at 25 °C)	LIMITS			UNIT
			MIN.	TYP.	MAX.	
Power Supply						
Quiescent current	I_Q	$V_{IN} = 3.3\text{ V}$, $I_{OUT} = 0\text{ mA}$	-	4.5	7	μA
Shutdown current	I_{SD}	OUT = GND	-	0.01	2	
Off switch current	$I_{DS(off)}$	EN = GND, OUT = GND	-	0.01	2	
Reverse blocking current	$I_{(in)RB}$	OUT = 5 V, IN = 1.2 V, EN = 0 V, (measured at IN pin)	-	0.01	1	
		OUT = 5 V, IN = 0 V, EN = 0 V, (measured at IN pin)	-	0.01	1	
Switch Resistance						
On resistance	$R_{DS(on)}$	$I_{OUT} = 500\text{ mA}$, $V_{IN} = 1.2\text{ V}$, $T_A = 25\text{ °C}$	-	95	150	m Ω
		$I_{OUT} = 500\text{ mA}$, $V_{IN} = 1.5\text{ V}$, $T_A = 25\text{ °C}$	-	80	120	
		$I_{OUT} = 500\text{ mA}$, $V_{IN} = 1.8\text{ V}$, $T_A = 25\text{ °C}$	-	70	100	
		$I_{OUT} = 500\text{ mA}$, $V_{IN} = 3\text{ V}$, $T_A = 25\text{ °C}$	-	54	65	
		$I_{OUT} = 500\text{ mA}$, $V_{IN} = 5\text{ V}$, $T_A = 25\text{ °C}$	-	50	65	
Discharge switch on resistance	R_{PD}	When $V_{IN} = 3\text{ V}$ at 25 °C	-	80	-	Ω
		When $V_{IN} = 1.8\text{ V}$ at 25 °C	-	< 200	-	
EN pin pulldown resistor	R_{EN}	EN = 1.2 V	1	2.6	5	M Ω
On resistance temperature coefficient	TC_{RDS}		-	2800	-	ppm/°C
On/off Logic						
EN input low voltage	V_{IL}	$V_{IN} = 1.5\text{ V}$	0.4	-	-	V
EN input high voltage	V_{IH}	$V_{IN} = 5.5\text{ V}$	-	-	1	

SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED $V_{IN} = 1.2\text{ V to }5.5\text{ V}$, $T_A = -40\text{ }^\circ\text{C to }+85\text{ }^\circ\text{C}$ (typical values are at $25\text{ }^\circ\text{C}$)	LIMITS			UNIT
			MIN.	TYP.	MAX.	
Switching Speed						
Switch turn-on delay time (SiP32461)	t_{on_DLY}	$R_{LOAD} = 500\ \Omega$, $C_L = 0.1\ \mu\text{F}$, $V_{IN} = 5\text{ V}$	-	130	-	μs
Switch turn-on rise time (SiP32461)	t_r	$R_{LOAD} = 500\ \Omega$, $C_L = 0.1\ \mu\text{F}$, $V_{IN} = 5\text{ V}$	-	170	-	
Switch turn-on time (including turn-on delay and rise time (SiP32462, fast switching))	t_{on}	$R_{LOAD} = 500\ \Omega$, $C_L = 0.1\ \mu\text{F}$, $V_{IN} = 5\text{ V}$	-	7.5	20	
Switch turn-off delay time	t_{off}	$R_{LOAD} = 500\ \Omega$, $C_L = 0.1\ \mu\text{F}$, (50 % V_{IN} to 90 % V_{OUT})	-	2	-	

PIN CONFIGURATION

Fig. 2 - WSCP 2 x 2 Package

DEVICE MARKING		
Row 1	Dot + W	: dot is A1 locator plus week code
Row 2	AB	: mark code for part number
SiP32460 = AF		
SiP32461 = AG		
SiP32462 = AH		

PIN DESCRIPTION (WSCP package)		
PIN#	NAME	FUNCTION
A1	OUT	Switch output
A2	IN	Switch input
B1	GND	Ground connection
B2	EN	Switch on/off control. A pull-down resistor is integrated

TRUTH TABLE	
EN	SWITCH
1	On
0	Off



BLOCK DIAGRAM

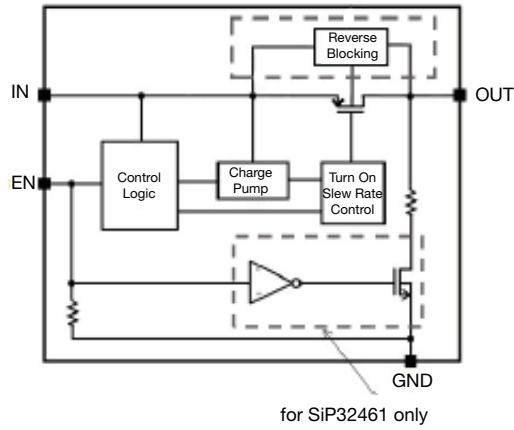


Fig. 3 - Functional Block Diagram

TYPICAL CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)

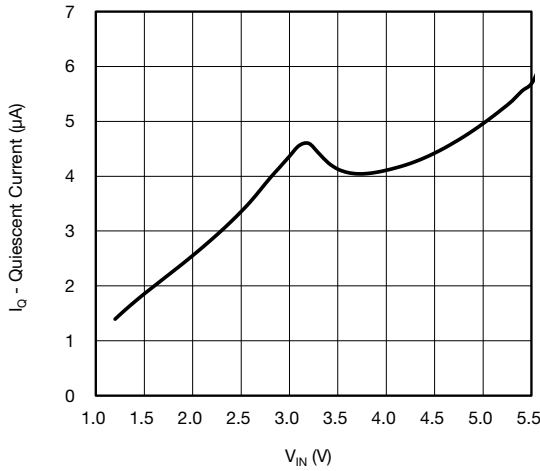


Fig. 4 - Quiescent Current vs. Input Voltage

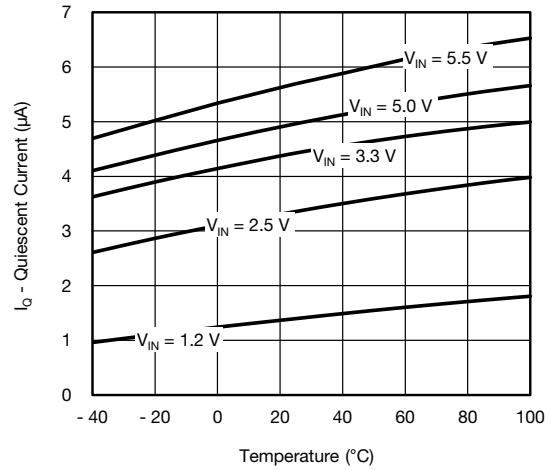


Fig. 7 - Quiescent Current vs. Temperature

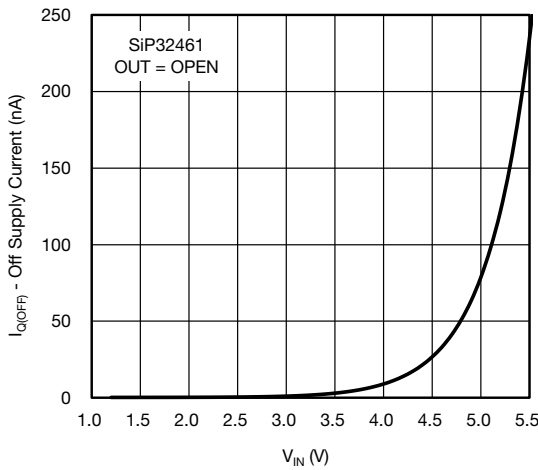


Fig. 5 - Off Supply Current vs. Input Voltage

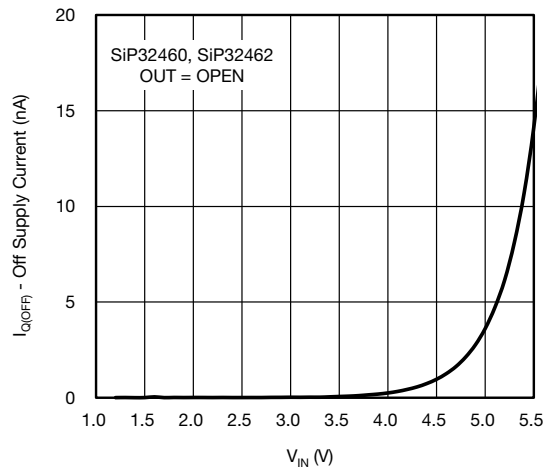


Fig. 8 - Off Supply Current vs. Input Voltage

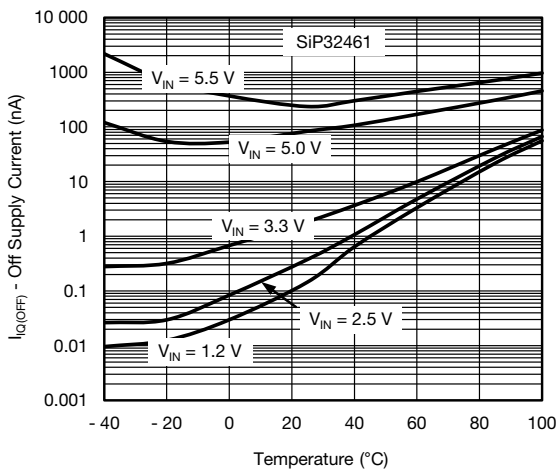


Fig. 6 - Off Supply Current vs. Temperature

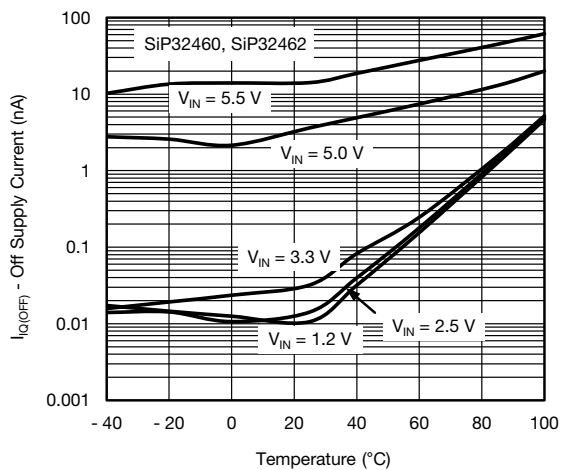


Fig. 9 - Off Supply Current vs. Temperature

TYPICAL CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)

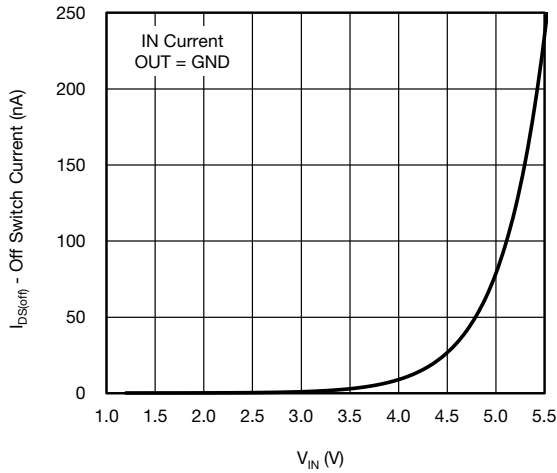


Fig. 10 - Off Switch Current vs. Input Voltage

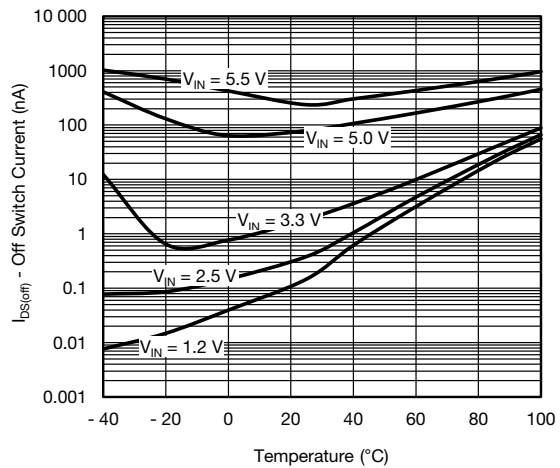


Fig. 13 - Off Switch Current vs. Temperature

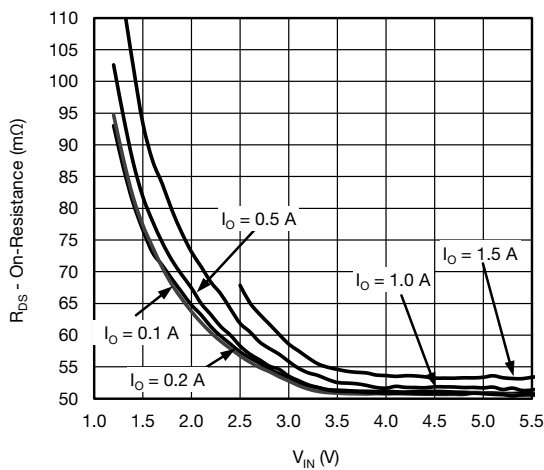


Fig. 11 - $R_{DS(on)}$ vs. Input Voltage

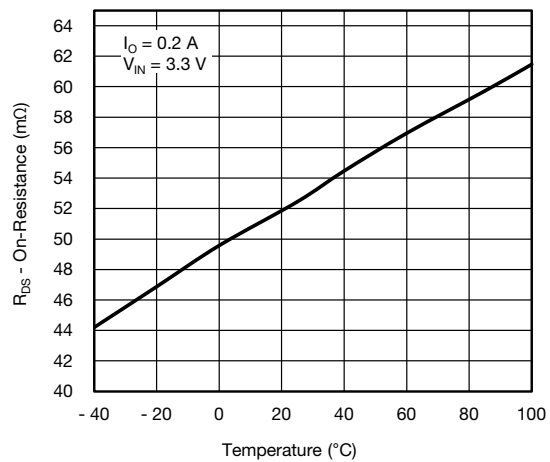


Fig. 14 - $R_{DS(on)}$ vs. Temperature

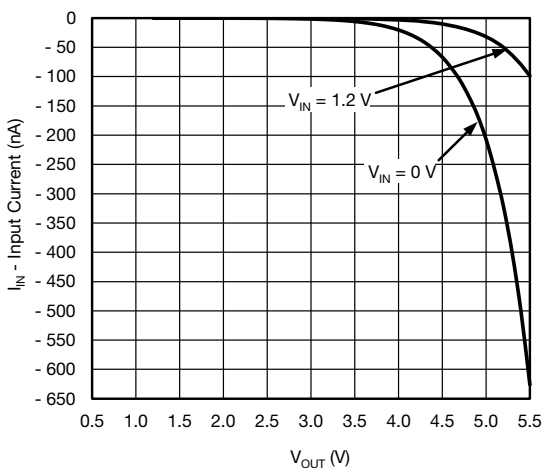


Fig. 12 - Reverse Blocking Current vs. Output Voltage

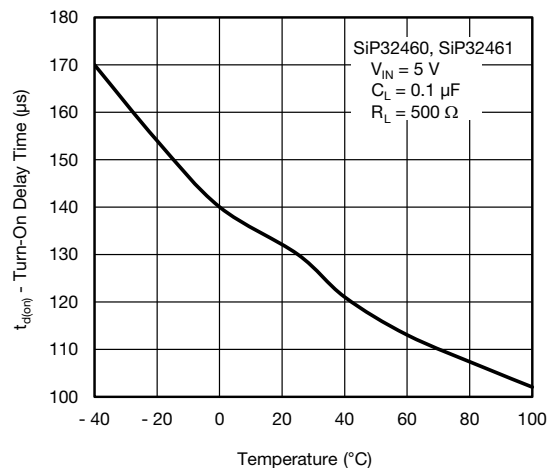


Fig. 15 - Turn-on Delay Time vs. Temperature



TYPICAL CHARACTERISTICS (T_J = 25 °C, unless otherwise noted)

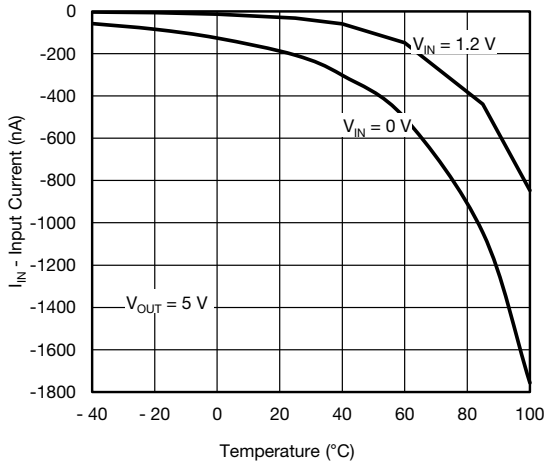


Fig. 16 - Reverse Blocking Current vs. Temperature

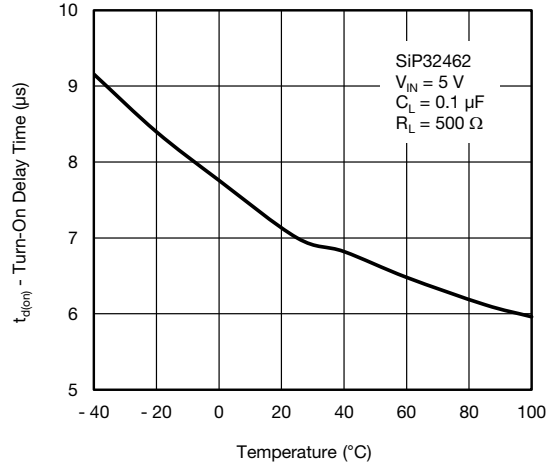


Fig. 19 - Turn-on Delay Time vs. Temperature

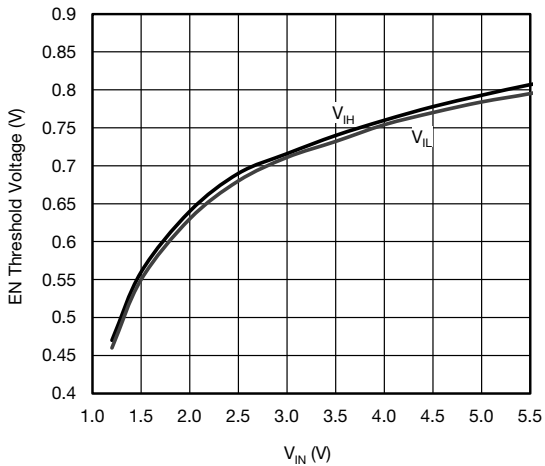


Fig. 17 - EN Threshold Voltage vs. Input Voltage

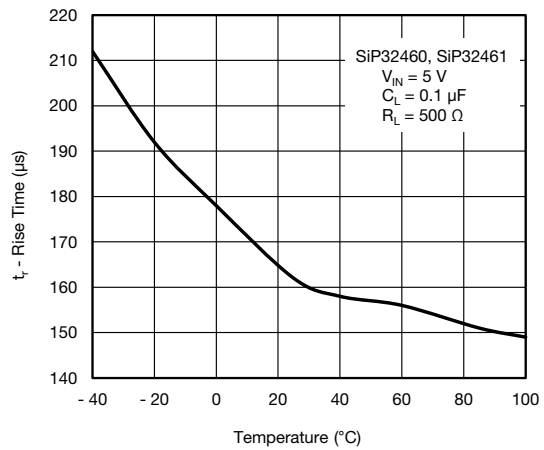


Fig. 20 - Rise Time vs. Temperature

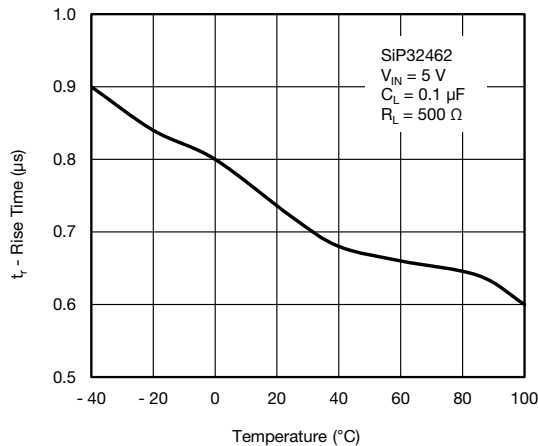


Fig. 18 - Rise Time vs. Temperature

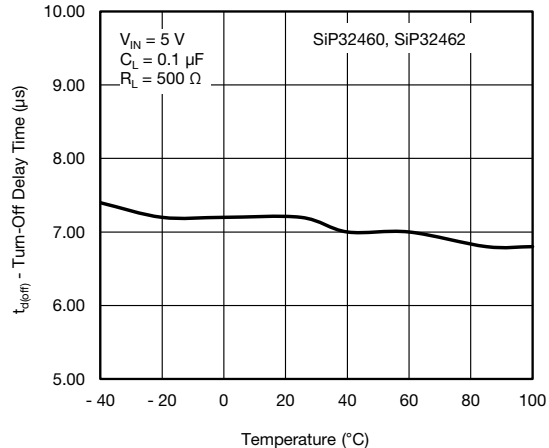


Fig. 21 - Turn-off Delay Time vs. Temperature

TYPICAL CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)

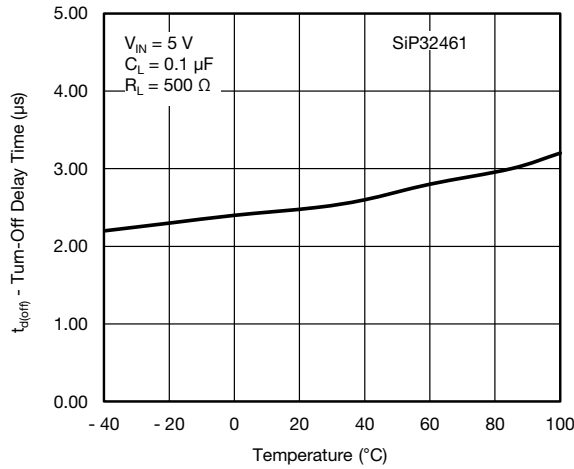


Fig. 22 - Turn-off Delay Time vs. Temperature

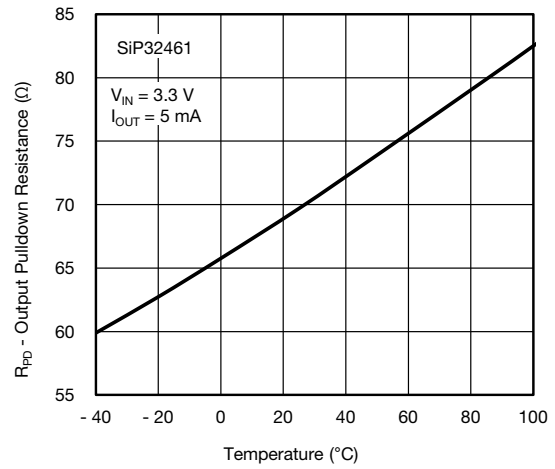


Fig. 23 - Output Pulldown Resistance vs. Temperature

TYPICAL WAVEFORMS

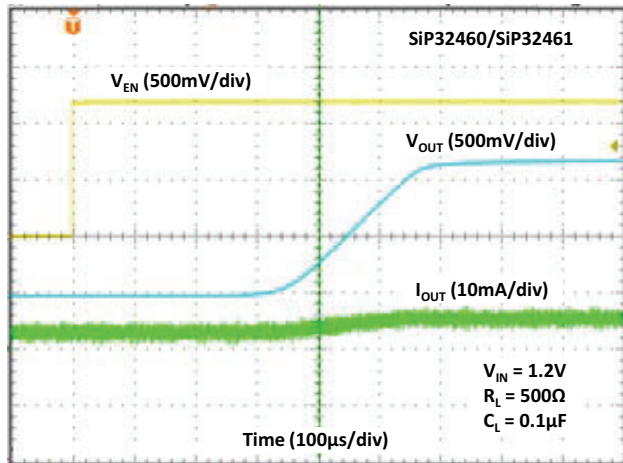


Fig. 24 - Turn-on Time

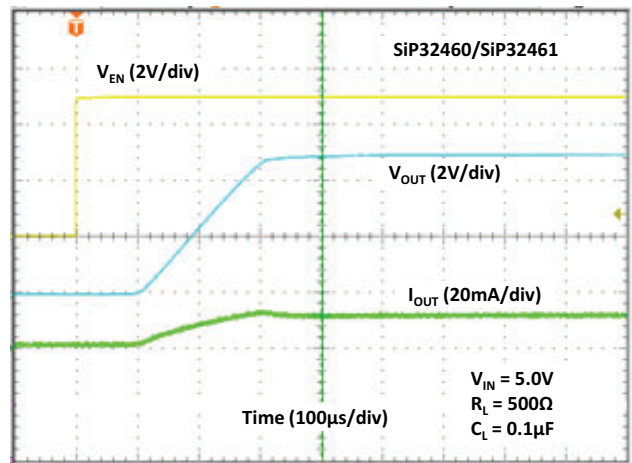


Fig. 25 - Turn-on Time



TYPICAL WAVEFORMS

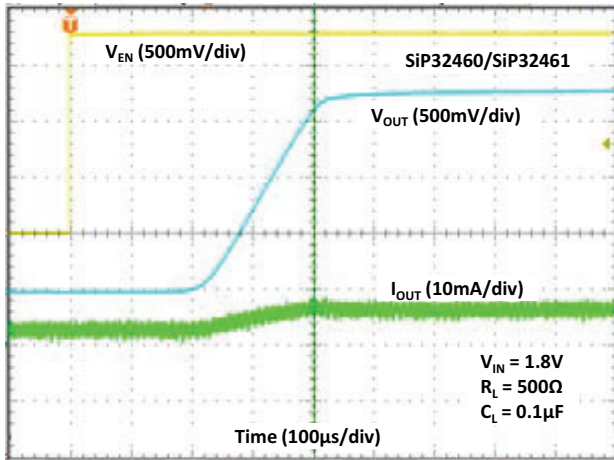


Fig. 26 - Turn-on Time

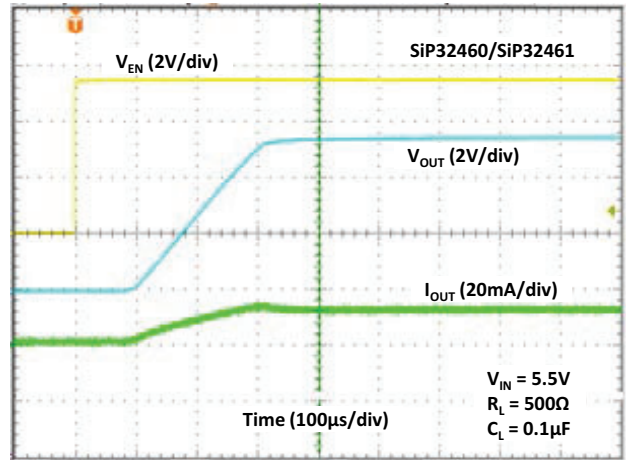


Fig. 29 - Turn-on Time

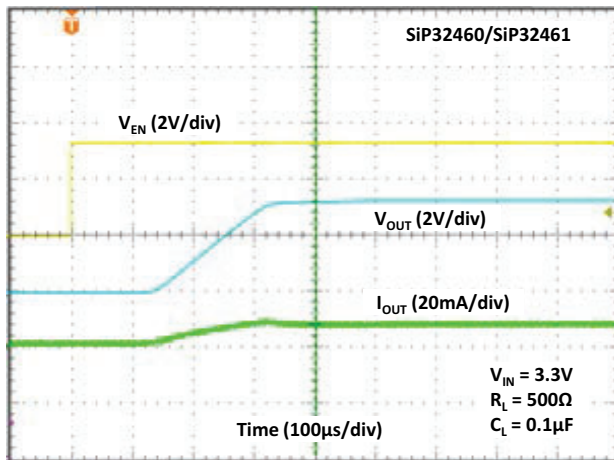


Fig. 27 - Turn-on Time

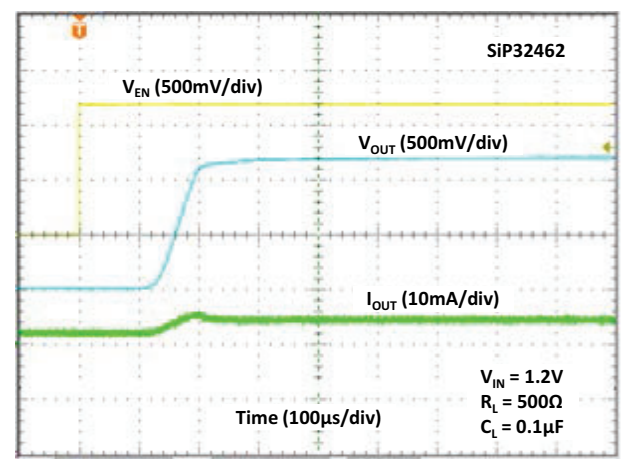


Fig. 30 - Turn-on Time

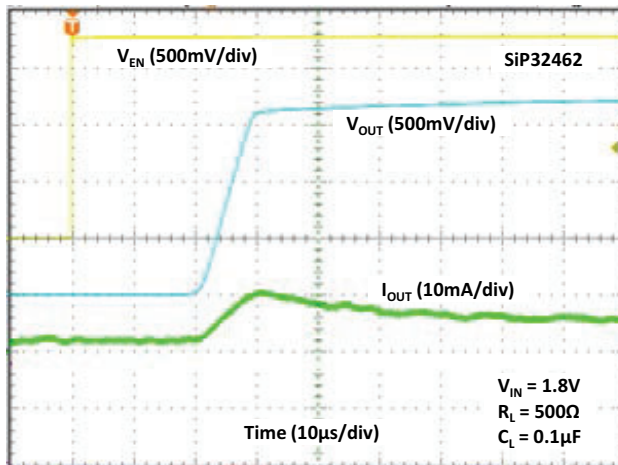


Fig. 28 - Turn-on Time

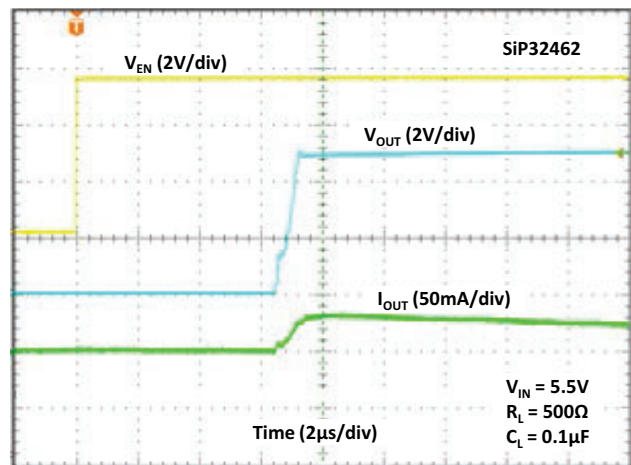


Fig. 31 - Turn-on Time



TYPICAL WAVEFORMS

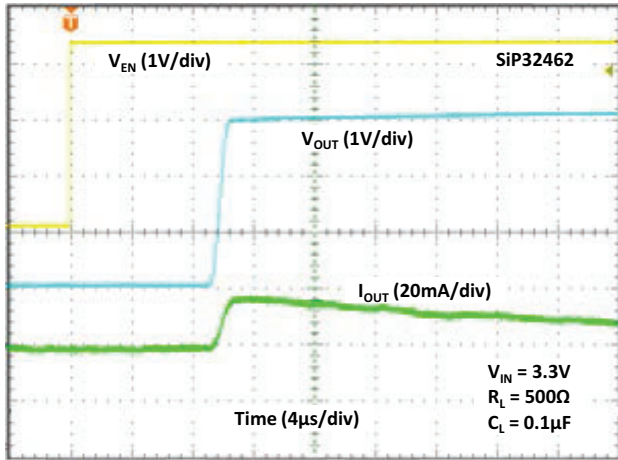


Fig. 32 - Turn-on Time

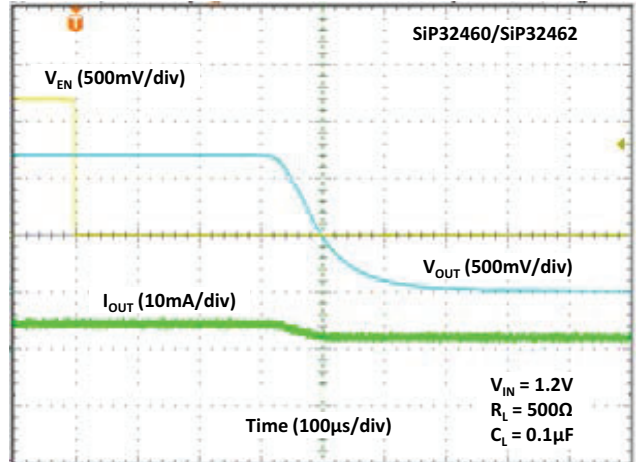


Fig. 35 - Turn-off Time

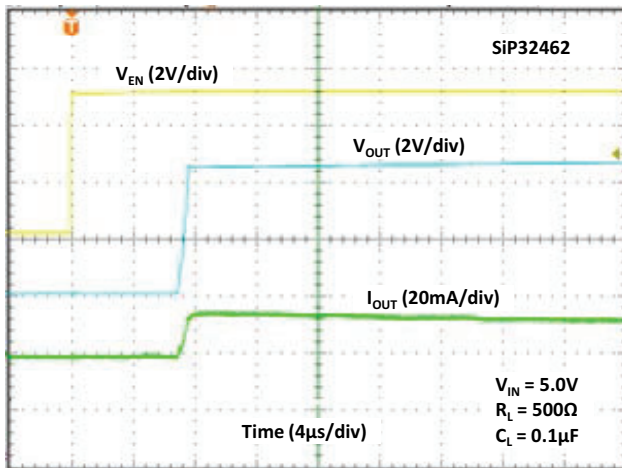


Fig. 33 - Turn-on Time

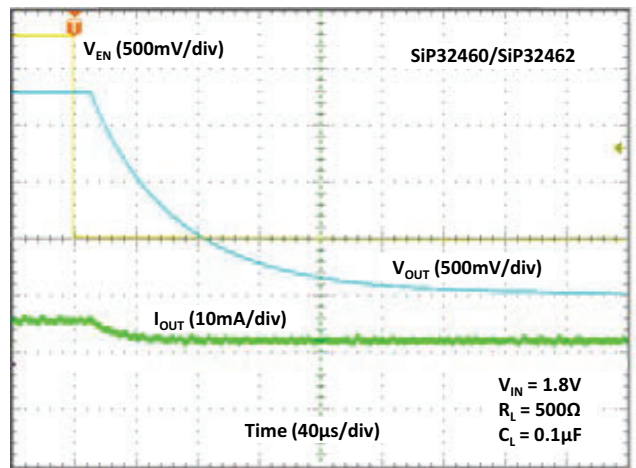


Fig. 36 - Turn-off Time

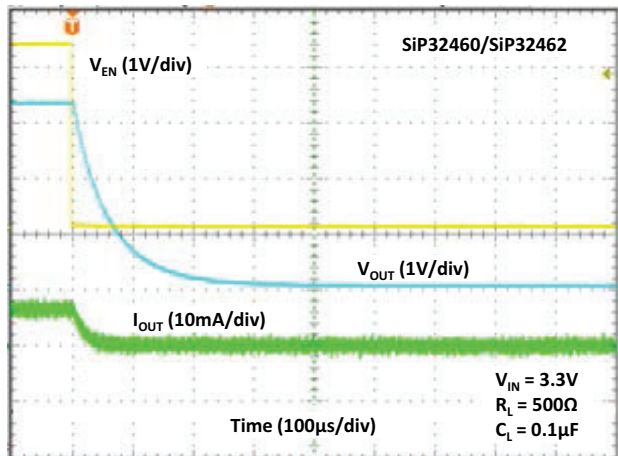


Fig. 34 - Turn-off Time

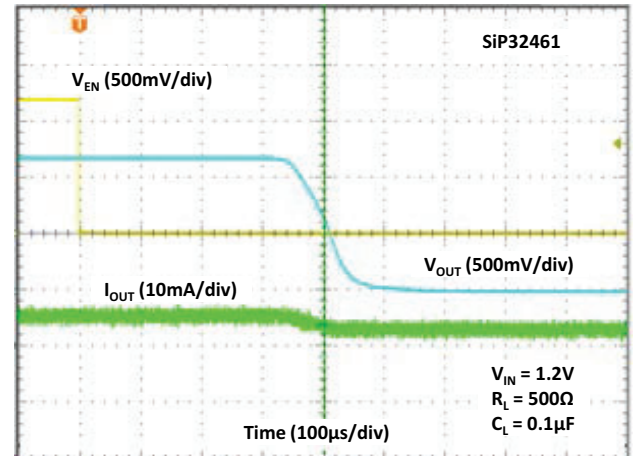


Fig. 37 - Turn-off Time



TYPICAL WAVEFORMS

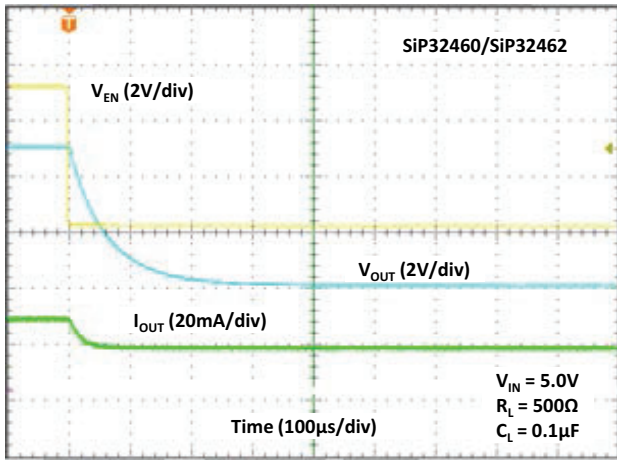


Fig. 38 - Turn-off Time

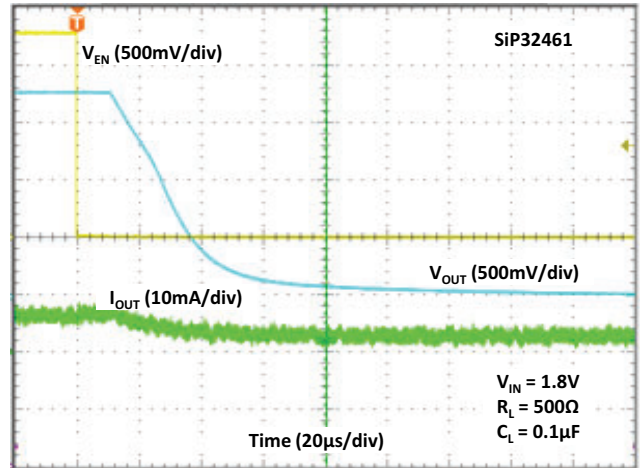


Fig. 41 - Turn-off Time

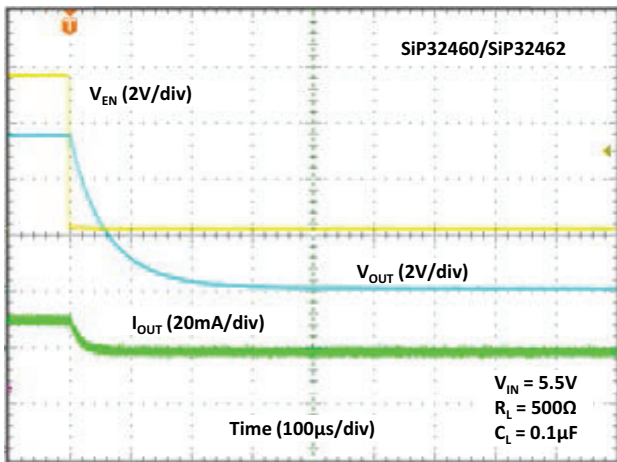


Fig. 39 - Turn-off Time

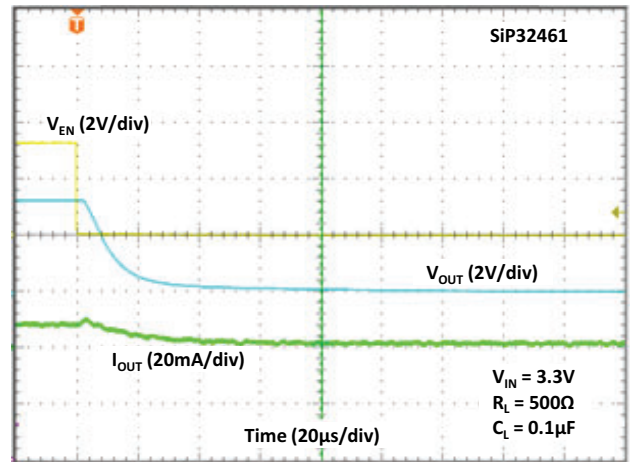


Fig. 42 - Turn-off Time

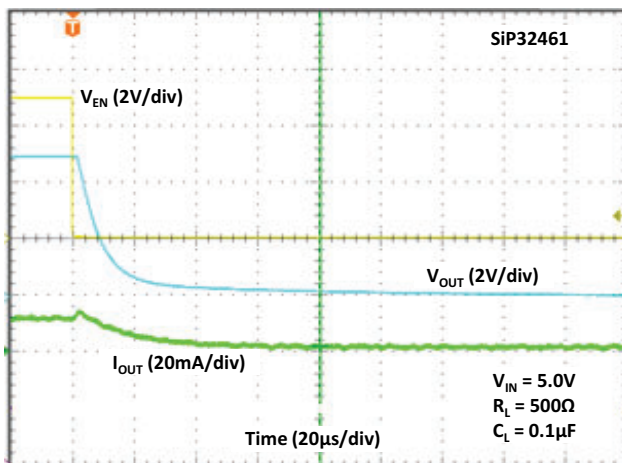


Fig. 40 - Turn-off Time

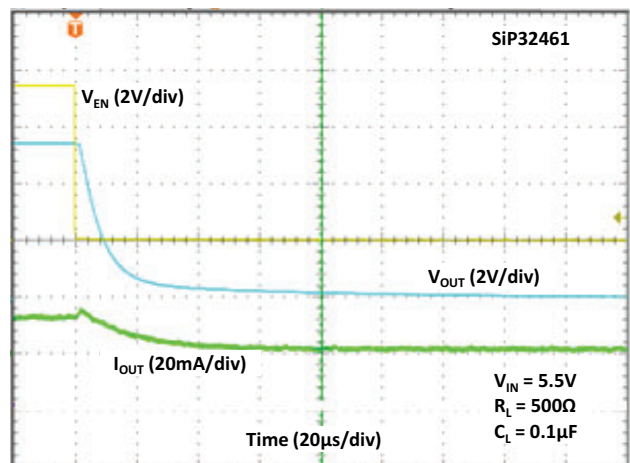


Fig. 43 - Turn-off Time



DETAILED DESCRIPTION

SiP32460, SiP32461, and SiP32462 are high side, slew rate controlled, load switches. They incorporate a negative charge pump at the gate to keep the gate to source voltage high when turned on. This keeps the on resistance low at lower input voltages. SiP32460 and SiP32461 are designed with slow slew rate to minimize inrush current during turn on. These devices have a reverse blocking circuit, when disabled, to prevent the current from going back to the input when the output voltage is higher than the input voltage. The SiP32460 and SiP32462 can be used as bidirectional switches and can be turned on and off when power is at either in or out. The SiP32461 has an output pulldown resistor to discharge the output capacitance when the device is off.

APPLICATION INFORMATION

Input Capacitor

While a bypass capacitor on the input is not required, a 4.7 μF or larger capacitor for C_{IN} is recommended in almost all applications. The bypass capacitor should be placed as physically close as possible to the input pin to be effective in minimizing transients on the input. Ceramic capacitors are recommended over tantalum because of their ability to withstand input current surges from low impedance sources such as batteries in portable devices.

Output Capacitor

A 0.1 μF capacitor across V_{OUT} and GND is recommended to insure proper slew operation. There is inrush current through the output MOSFET and the magnitude of the inrush current depends on the output capacitor, the bigger the C_{OUT} the higher the inrush current. There is no ESR or capacitor type requirement.

Enable

The EN pin is compatible with CMOS logic voltage levels. It requires at least 0.4 V or below to fully shut down the device and 1 V or above to fully turn on the device. There is a 2.6 MΩ resistor connected between EN pin and GND pin.

Protection Against Reverse Voltage Condition

This device contains a reverse blocking circuit. When disabled (V_{EN} less than 0.4 V) this circuit keeps the output current from flowing back to the input when the output voltage is higher than the input voltage.

Thermal Considerations

Due to physical limitations of the layout and assembly of the device the maximum switch current is 1.2 A as stated in the Absolute Maximum Ratings table. However, another limiting

characteristic for the safe operating load current is the thermal power dissipation of the package.

The maximum power dissipation in any application is dependent on the maximum junction temperature, T_{J(max.)} = 125 °C, the junction-to-ambient thermal resistance, θ_{J-A} = 205 °C/W, and the ambient temperature, T_A, which may be expressed as:

$$P \text{ (max.)} = \frac{T_{J(max.)} - T_A}{\theta_{JA}} = \frac{125 - T_A}{205}$$

It then follows that, assuming an ambient temperature of 70 °C, the maximum power dissipation will be limited to about 268 mW.

So long as the load current is below the 1.2 A limit, the maximum continuous switch current becomes a function two things: the package power dissipation and the R_{DS(on)} at the ambient temperature.

As an example let us calculate the worst case maximum load current at T_A = 70 °C. The worst case R_{DS(on)} at 25 °C is 120 mΩ at V_{IN} = 1.5 V. The R_{DS(on)} at 70 °C can be extrapolated from this data using the following formula:

$$R_{DS(on)} \text{ (at 70 °C)} = R_{DS(on)} \text{ (at 25 °C)} \times (1 + T_C \times \Delta T)$$

Where T_C is 2800 ppm/°C. Continuing with the calculation we have

$$R_{DS(on)} \text{ (at 70 °C)} = 120 \text{ m}\Omega \times (1 + 0.0028 \times (70 \text{ °C} - 25 \text{ °C})) = 135 \text{ m}\Omega$$

The maximum current limit is then determined by

$$I_{LOAD(max.)} < \sqrt{\frac{P \text{ (max.)}}{R_{DS(on)}}}$$

which in this case is 1.99 A. Under the stated input voltage condition, if the 1.99 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.

To avoid possible permanent damage to the device and keep a reasonable design margin, it is recommended to operate the device maximum up to 1.2 A only as listed in the Absolute Maximum Ratings table.

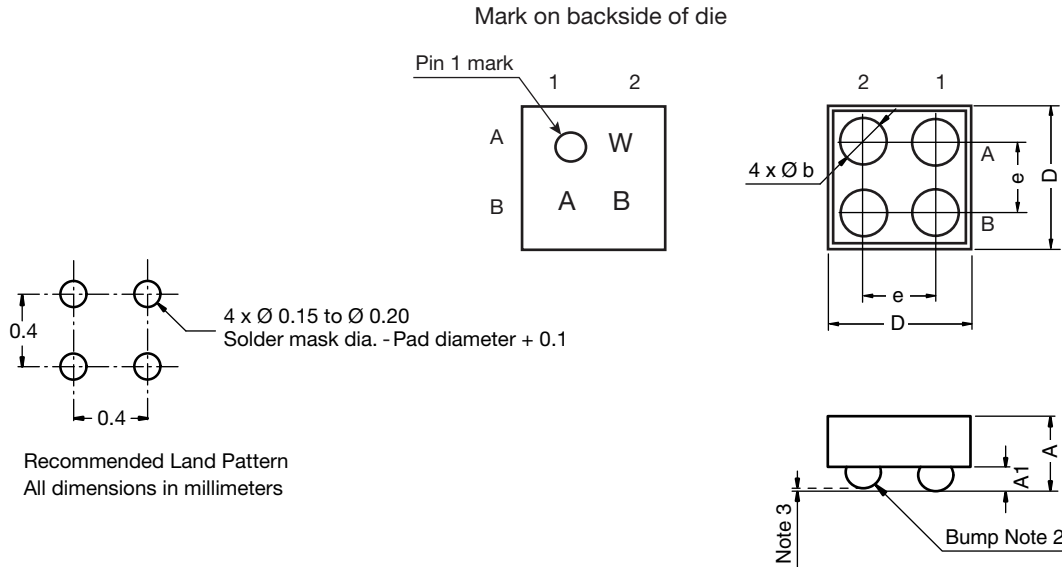


PRODUCT SUMMARY			
Part number	SiP32460	SiP32461	SiP32462
Description	1.2 V to 5.5 V, 50 mΩ, 200 μs rise time, bidirectional off isolation	1.2 V to 5.5 V, 50 mΩ, 200 μs rise time, bidirectional off isolation, output discharge	1.2 V to 5.5 V, 50 mΩ, 7.5 μs rise time, bidirectional off isolation
Configuration	Single	Single	Single
Slew rate time (μs)	170	170	7.5
On delay time (μs)	130	130	-
Input voltage min. (V)	1.2	1.2	1.2
Input voltage max. (V)	5.5	5.5	5.5
On-resistance at input voltage min. (mΩ)	95	95	95
On-resistance at input voltage max. (mΩ)	50	50	50
Quiescent current at input voltage min. (μA)	1.2	1.2	1.2
Quiescent current at input voltage max. (μA)	5.5	5.5	5.5
Output discharge (yes / no)	No	Yes	No
Reverse blocking (yes / no)	Yes	Yes	Yes
Continuous current (A)	1.2	1.2	1.2
Package type	WCSP4	WCSP4	WCSP4
Package size (W, L, H) (mm)	0.8 x 0.8 x 0.5	0.8 x 0.8 x 0.5	0.8 x 0.8 x 0.5
Status code	2	2	2
Product type	Slew rate	Slew rate	Slew rate
Applications	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?67754

WCSP4: 4 Bumps

(2 x 2, 0.4 mm pitch, 208 μm bump height, 0.8 mm x 0.8 mm die size)



DWG-No: 6004

Notes

- (1) Laser mark on the backside surface of die
- (2) Bumps are SAC396
- (3) 0.05 max. coplanarity

DIM.	MILLIMETERS ^a			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.515	0.530	0.545	0.0203	0.0209	0.0215
A1	0.208			0.0082		
b	0.250	0.260	0.270	0.0098	0.0102	0.0106
e	0.400			0.0157		
D	0.720	0.760	0.800	0.0283	0.0299	0.0315

Note

- a. Use millimeters as the primary measurement



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.


Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 [View SIP32462DB-T2-GE1 on WIN SOURCE](#)

 [Vishay Information](#)

Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management